

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1625	365/185.18.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:41
L2	528	365/185.26.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:41
L3	507	365/185.01.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:41
L4	2281	365/226.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:41
L5	14950	programm\$3 same EEPROM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:41
L6	213	L5 same transistor same (P\$1type or P\$1well or P\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:41
L7	148	L6 same (N\$1well\$1 or N\$1type or N\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
L8	18	7 and 1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43

L9	6	7 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
L10	8	7 and 3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
L11	8	7 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
L12	3037	L5 and transistor and (P\$1type or P\$1well or P\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
L13	66	L12 and (N\$1well or N\$1type or N\$1channel) and (first adj3 positive adj3 voltage) and (second adj3 positive adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
L14	31	L13 and (first adj3 negative adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
L15	27	L14 and "365"/\$7.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
L16	21	L15 and current and bias\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:44

L17	0	16 and 1 and 2 and 3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:44
L18	2	16 and 1 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:44
L19	8	16 and 1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:44
L20	9	16 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:44
L21	0	16 and 3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:44
L22	19	365/185.18 and EEPROM and (first adj3 positive adj3 voltage) and (second adj3 positive adj3 voltage) and (first adj3 negative adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:45
L23	8	L22 and current\$3 and electron and bias	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:45
S25	14115	programm\$3 same EEPROM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:24

S26	211	S25 same transistor same (P\$1type or P\$1well or P\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:28
S27	146	S26 same (N\$1well or N\$1type or N\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:41
S28	33	S27 and 365/185.18,185.01,185.26,226.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:26
S29	18	S27 and 365/185.18.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:27
S30	2	S27 same (first adj3 voltage) same (second adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:27
S31	40	S27 and (first adj3 voltage) and (second adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:27
S32	33	S31 and "365"/\$7.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:28
S33	2926	S25 and transistor and (P\$1type or P\$1well or P\$1channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:28

S34	64	S33 and (N\$1well or N\$1type or N\$1channel) and (first adj3 positive adj3 voltage) and (second adj3 positive adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:29
S35	30	S34 and (first adj3 negative adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:29
S36	26	S35 and "365"/\$7.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:30
S37	16	S36 and current and bias	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:43
S38	0	(programm\$3 and EEPROM and transistor and (P\$1well or P\$1type) and (N\$1well or N\$1type) and (first adj3 voltage) and (second adj3 voltage) and bit\$1line and current and bias and electron).CLM.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:32
S39	93	chen-chen.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:32
S40	0	chen-chen-c.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:32
S41	174	chen-chen-\$in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:32

S42	1	huang-shui.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:33
S43	0	huang-shui-c.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:33
S44	17	huang-shui-\$.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:33
S45	18	365/185.18 and EEPROM and (first adj3 positive adj3 voltage) and (second adj3 positive adj3 voltage) and (first adj3 negative adj3 voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 08:34
S46	8	S45 and current and electron and bias	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/23 11:45